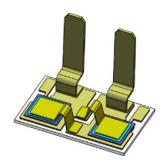


Rev.0.5 Oct.20 2023

DBC040C/16KQ

Description

- 1) Components adopt vacuum welding to well control void and rated voltage up to 1600V.
- 2) A package of two inverse parallel SCRs.
- 3) Thyristor chips are welding on the ceramic copper clad laminate, products with high electricity ability, excellent heat dissipation ability.



Typical Application

Constant temperature system, CNC machine, remote control system, lighting control, power compensation and so on.

Absolute Maximum Ratings (Packaged into modules, unless otherwise specified, T_{CASE}=25℃)

	, ,			
Parameter	Test Conditions	Symbol	Values	Unit
Operating junction temperature range		TJ	-40~+125	$^{\circ}$
Repetitive peak off-state voltage	TJ=25℃	VDRM	1600	V
Repetitive peak reverse voltage	TJ=25°C	VRRM	1600	V
Non-repetitive peak off-state voltage	TJ=25℃	V _{DSM}	1700	V
Non-repetitive peak reverse voltage	TJ=25℃	VRSM	1700	V
Average on-state current	Tc=80℃	I _{T(AV)}	40	Α
RMS on-state current	Tc=80℃	I _{T(RMS)}	60	Α
Non-repetitive surge peak on-state current	t _P =10ms V _R =0.6V _{RRM}	I _{TSM}	800	А
I ² t value for fusing	t _P =10ms V _R =0.6V _{RRM}	l ² t	3200	A ² s
Critical rate of rise of on-state current	Ig =2×Igт	di/dt	150	A/µs

Electrical Characteristics (Packaged into modules, unless otherwise specified, T_{CASE}=25°C)

Parameter	Test Conditions	Symbol	Values	Unit
Peak on-state voltage	I _{TM} =120A,t _P =380µs	Vтм	≤1.8	V
	V _D =V _{DRM}			
Repetitive peak off-state current	Tc=25℃	I _{DRM1}	≤50	μA
	Tc=125℃	I _{DRM2}	≤10	mA

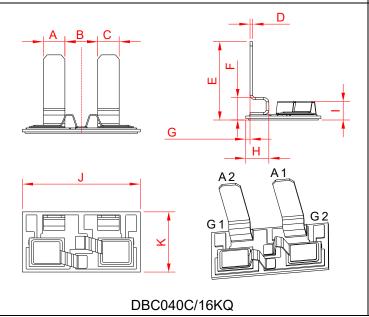


Solid DBC Modules

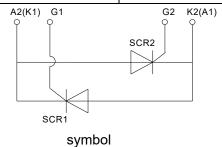
	V _R =V _{RRM}			
Den etition and the second			450	
Repetitive peak reverse current	Tc=25°C	IRRM1	≤50	μA
	Tc=125℃	I _{RRM2}	≤10	mA
Triggering gate current	V _D =12V R _L =30Ω	lgт	10-80	mA
Latching current	Ig=1.2 Igт	lι	≤250	mA
Holding current	I _T =1A	Ін	≤150	mA
Triggering gate voltage	$V_D=12V R_L=30\Omega$	V _{GT}	≤1.3	V
Non triggering gate voltage	V _D =V _{DRM} T _J =125°C	V_{GD}	≥0.2	V
Critical rate of rise of voltage	V _D =2/3V _{DRM} T _J =125℃ Gate Open	dv/dt	≥1000	V/µs

Mechanical Characteristics

Chip size	7.6mm×7.6mm
Module size	22mm×14mm
Terminal height	19.2mm
Solder composition and melting point of DBC	Solder composition: Pb92.5%Sn5%Ag2.5%; melting point>295°C.



	Dimensions					
Ref	M	Millimeters			Inches	
	Min	Тур	Max	Min	Тур	Max
Α	3.7	4.0	4.3	0.146	0.157	0.169
В	5.6	6.1	6.6	0.220	0.240	0.260
С	3.7	4	4.3	0.146	0.157	0.169
D	0.3	0.5	0.7	0.012	0.020	0.028
E			19.2			0.756
F			6.2			0.244
G	0.3	0.8	1.3	0.012	0.031	0.051
Н	3.8	4.3	4.8	0.150	0.169	0.189
1			6	0.000	0.000	0.236
J	21.7	22	22.3	0.854	0.866	0.878
K	13.7	14	14.3	0.539	0.551	0.563

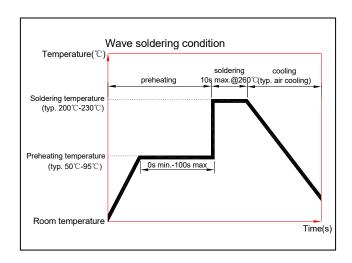






Soldering Process Requirements

a. Hand soldering iron welding			
Soldering temperature	≤260℃		
Soldering time	≤10s		
b. Wave soldering (see figure at right)			
Preheating temperature	≤125℃		
Preheating time	≤100s		
Soldering temperature	≤260℃		
Soldering time	≤10s		

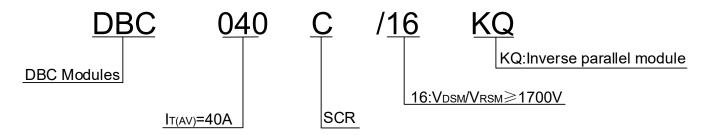


Working Conditions

- 1) No severe mechanical shock as impact and drop off in the process of transportation, storage and working of product.
- 2) Storage conditions
 Temperature: 5~40°C
 Relative humidity: ≤45%

Storage time: 3 days for the open package; 3 months for the closed package

Ordering Information



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